

Unipolar Hall Effect Switches

Description

The SC113X Hall-Effect switch series is monolithic integrated circuits with tighter magnetic specifications, designed to operate continuously over extended temperatures to $+150^{\circ}$ C, and are more stable with both temperature and supply voltage changes. The negative compensation slope is optimized to match the negative temperature coefficient of low cost magnets.

Each device includes a voltage regulator for operation with supply voltages of 3.8 to 40V volts, quadratic Hall-voltage generator, temperature compensation circuitry, small-signal amplifier, Schmitt trigger, and an open-collector output to sink up to 40mA.

Features and Benefits

- 3.8 to 40V supply voltage
- High transient voltage protection
- 40mA sinking capability
- High ESD rating
- 3-pin SIP, 3-pin SOT-89 and SOT-23 packages are available
- RoHs compliant

Potential Applications

- Brushless DC motor
- Position sensor
- Motor and fan control
- Auto-motive transmission position



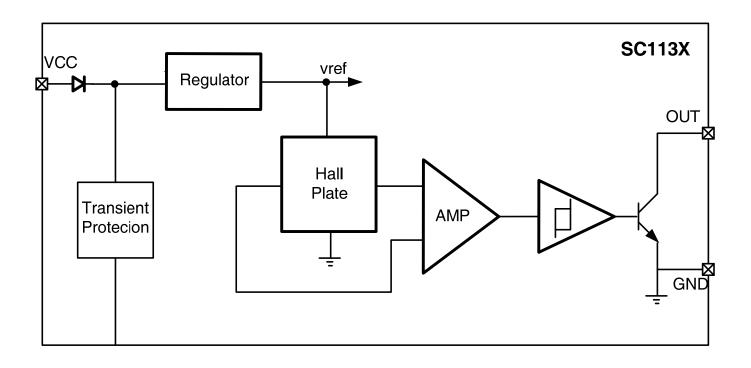
Device Information

Part Number	Packing	Mounting	Ambient, T _A	B _{оР} (Тур.)	B _{RP} (Typ.)	
SC1133UA	Bulk, 1000 pieces/bag	SIP3		+8.0mT	+5.5mT	
SC1133SO-N	Reel, 3000pieces/reel	SOT-23	-40℃ to 150℃	-8.0mT	-5.5mT	
SC1134UA	Bulk, 1000 pieces/bag	SIP3		40.0 T	0.5. T	
SC1134BU	Reel, 1000pieces/reel	SOT-89	-40°C to 150°C	+12.0mT	+9.5mT	
SC1134SO-N	Reel, 3000pieces/reel	SOT-23		-12.0mT	-9.5mT	
SC1138UA	Bulk, 1000 pieces/bag	SIP3	4000 1 45000	+25.0mT	+20.0mT	
SC1138SO-N	Reel, 3000pieces/reel	SOT-23	-40℃ to 150℃	-25.0mT	-20.0mT	



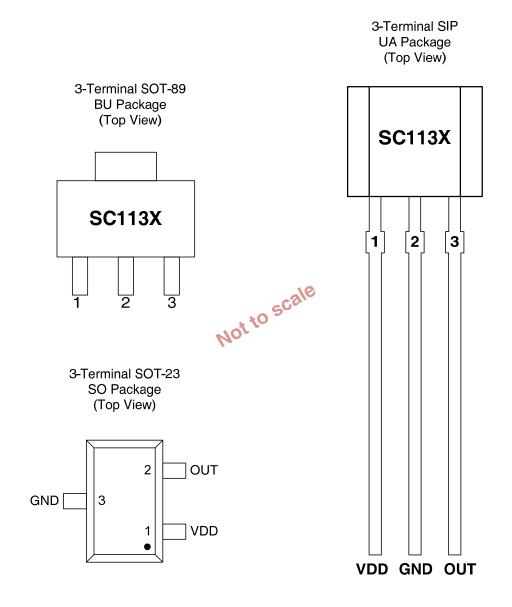
Block Diagram

The circuit includes Hall generator, amplifier and Schmitt-Trigger on one chip. The internal reference provides the supply voltage for the components. A magnetic field perpendicular to the chip surface induces a voltage at the Hall probe. This voltage is amplified and switches as a Schmitt-Trigger with open-collector output. A protection diode against reverse power supply is integrated.





Pin Description



Terminal					
Nomo	Name		Туре	Description	
Name	UA/BU	SO			
VDD	1	1	PWR	3.8 to 40 V power supply	
GND	2	3	Ground	Ground terminal	
OUT	3	2	Output	Open-drain output	



Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

Parameter	Symbol	Min.	Max.	Units
Power supply voltage	V _{CC}	-40 ⁽²⁾	60	V
Output terminal voltage	Vout	-0.5	60	V
Output terminal current sink	Isink	0	50	mA
Operating ambient temperature	TA	-40	150	°C
Maximum junction temperature	TJ	-55	165	°C
Storage temperature	Тѕтс	-65	175	°C

⁽¹⁾Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

⁽²⁾Ensured by design.

Electrical Characteristics

over operating free-air temperature range (Vcc =5V, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Vcc	Operating voltage ⁽¹⁾	TJ < TJ (Max.)	3.8		40	V
VCCR	Reverse supply voltage	T _A =25℃	-40			V
lcc	Operating supply current	Vcc=3.8 to 40 V		4.0	10	mA
IQL	Off-state leakage current	Output Hi-Z			3	uA
Vsat	Output saturation voltage	I <mark>Q</mark> =20mA, T _A =25℃			300	mV
tr	Output rise time	R1=1Kohm Co=20pF			1.5	uS
tr	Output fall time	R1=1Kohm Co=20pF			1.5	uS

⁽¹⁾ Maximum voltage must be adjusted for power dissipation and junction temperature, see Thermal Characteristics

⁽²⁾ 1mT=10Gs



Magnetic Characteristics

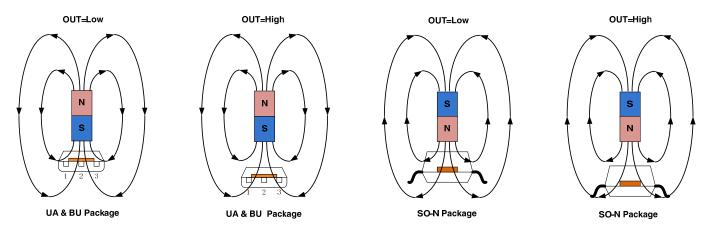
over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units		
fвw	Bandwidth				100	kHz		
SC1133 +8.0 / +5.5 mT								
BOP	Operated point		5.5	8.0	11.5	mT		
Brp	Release point	T ₄=25 ℃	1.5	5.5	10.0	mT		
BHYS	Hysteresis			2.5		mT		
SC1134 +12.0 / +9.5 mT								
Вор	Operated point		9.5	12.0	16.5	mT		
Brp	Release point	T ₄=25℃	5.5	9.5	14.0	mT		
B _{HYS}	Hysteresis			2.5		mT		
SC1138 +25.0 / +20.0 mT								
BOP	Operated point	T₄=25℃	20.5	25.0	29.5	mT		
B _{RP}	Release point		14.5	20.0	25.5	mT		
BHYS	Hysteresis			5.0		mT		



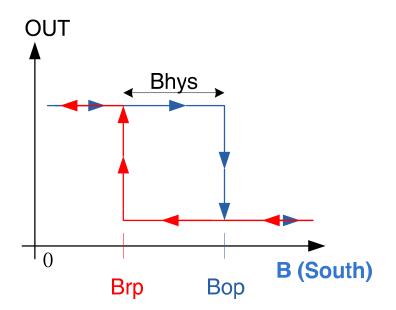
Field Direction Definition

A positive magnetic field is defined as a South pole near the marked side of the package.



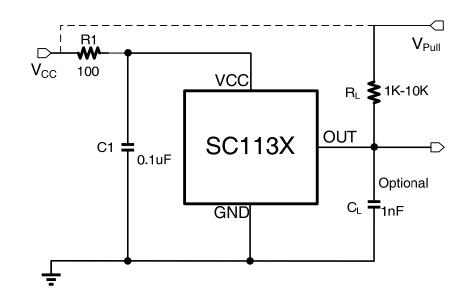
Transfer Function

Powering-on the device in the hysteresis region, less than B_{OP} and higher than B_{RP} , allows an indeterminate output state. The correct state is attained after the first excursion beyond B_{OP} or B_{RP} . If the field strength is greater than B_{OP} , then the output is pulled low. If the field strength is less than B_{RP} , the output is released.





Typical Application



The SC113X contains an on-chip voltage regulator and can operate over a wide supply voltage range. In applications that operate the device from an unregulated power supply, transient protection must be added externally. For applications using a regulated line, EMI/RFI protection may still be required. R1 is for improved CI performance, and could be 100 or 200 Ω typically.

The SC113X device output stage uses an open-drain NPN transistor, and it is rated to sink up to 40mA of current. For proper operation, calculate the value of the pull-up resistor R_L is required. The size of R_L is a tradeoff between OUT rise time and the load capacity when OUT is pulled low. A lower current is generally better, however faster transitions and bandwidth require a smaller resistor for faster switching.

Select a vaule for C_L based on the system bandwidth specifications as:

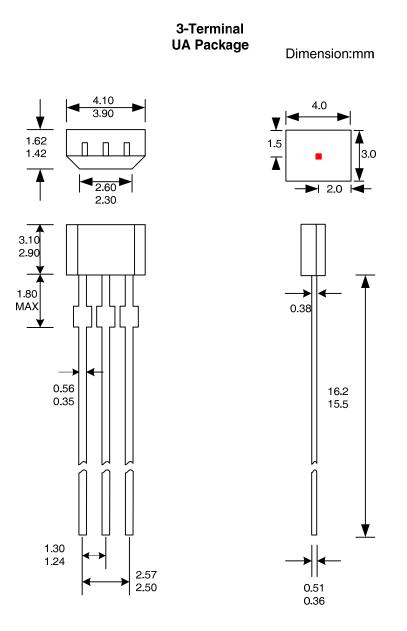
$$2 \times f(Hz) = \frac{1}{2\pi \times R \times C}$$

Most applications do not require this C_L filtering capacitor.

 V_{PULL} is not restricted to V_{CC} , and could be connected to other voltage reference. The allowable voltage range of this terminal is specified in the Absolute Maximum Ratings.



Mechanical Dimensions



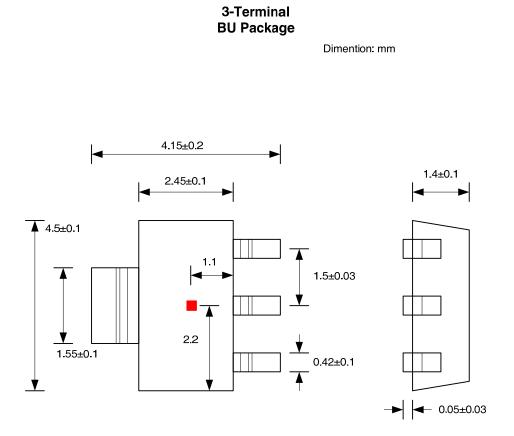
Notes:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Height does not include mold gate flash.

Where no tolerance is specified, dimension is nominal.



Mechanical Dimensions



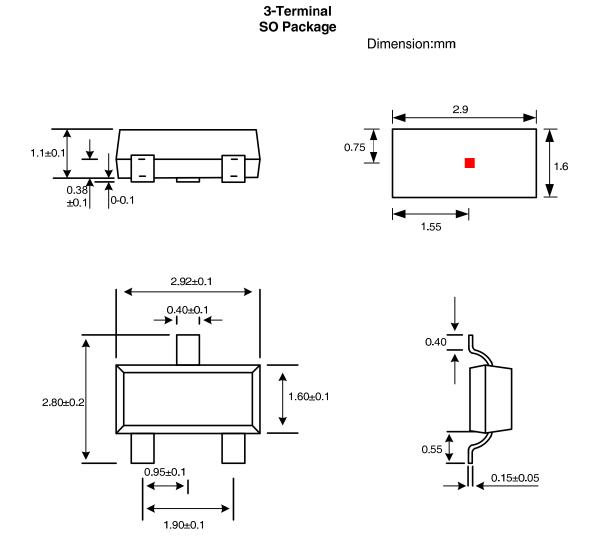
Notes:

- Exact body and lead configuration at vendor's option within limits shown. Height does not include mold gate flash. 1.
- 2.

Where no tolerance is specified, dimension is nominal.



Mechanical Dimensions



Notes:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Height does not include mold gate flash.

Where no tolerance is specified, dimension is nominal.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Industrial Hall Effect/Magnetic Sensors category:

Click to view products by Semiment manufacturer:

Other Similar products are found below :

 GT-13013
 GT-14040
 GT-14114
 DRR-129(62-68)
 ATS682LSHTN-T
 SR4P2-C7
 GT-13012
 GT-14049
 GT-14067
 GT-14132
 GT-18030

 103FW12-R3
 A1155LLHLT-T
 SMSA2P30CG
 P2D-000
 GN 55.2-SC-15-3
 GN 55.2-SC-5-3
 MZA70175
 103FW41-R1
 KJR-D100AN

 DNA-VE
 KJR-D100AN-DNIA-V2
 SR-10018
 115L
 14E 502
 W06017
 ATS128LSETN-T
 TLE4906LHALA1
 TLE49452LHALA1

 BU52013HFV-TR
 MRMS591A
 103SR14A-1
 MZT7-03VPS-KR0
 MZT7-03VPS-KW0
 MZT8-03VPS-KW0
 MZT8-28VPS-KP0

 A1326LLHLX-T
 A1326LLHLT-T
 A1156LLHLT-T
 ACS770LCB-100U-PFF-T
 ATS617LSGTN-T
 AH49ENTR-G1
 SS360PT
 SS311PT

 GN 55.2-ND-15-3
 GN 55.2-ND-18-3
 GN 55.2-ND-8-3
 GN 55.2-SC-10-3
 GN 55.4-ND-10-7,5-2
 GN 55.4-ND-12-9,5-2,5

 GN 55.4-ND-26-20,3-5
 GN 55.4-ND-7,5-4-1,5
 SN 55.4-ND-26-20,3-5
 GN 55.4-ND-7,5-4-1,5